	Re	evisions	
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Α	12/31/2008		

STRESS AND DERATING ANALYSIS

Modular Platform

12V Converter

PREPARED BY

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December 31, 2008

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BREAK EDGES .005/.020 FILLET RADIUS .005/.020			
SURFACE ROUGHNESS - 64 RMS INTERPRET PER SRC DRM.			



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	Size	Date	DWG NO	REV
SDRL 0001	Α	31-Dec-08	12V Converter	
SDRL 0001	Scale	Cage code		
	N/A			

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1.0 Stress/Derating Analysis

1.1 Scope

This document contains the nominal and worst case stress and derating analysis results for the 12V DC-DC Converter Module. The nominal and worst case (WC) circuit performance values are compared to recommended deratings to investigate whether components are used within their operational limits and that no overstress conditions exist.

Analysis:	Stress & Derating Analysis
Performed by:	SS, DF, PH, DC
Last Rev Date:	6/16/2011
Assembly:	12V Converter Module
Schematics:	Converter Schematic.pdf
Excel Files:	I Worst Case Stress.xls
Other Files:	stress calculations.mcd stress calculations.pdf BOM with Component Manufacturer info.xls

1.2 Applicable Documents

- Mil-Handbook-1547 Electronic Parts, Materials, And Processes For Space And Launch Vehicles, 06 July 1998
- Mil-Std-975M NASA Standard Electrical, Electronic, And Electromechanical (EEE)
 Parts List, 5 August 1994
- 3. Electronic Derating for Optimum Performance Reliability Analysis Center, 15-11, 2000
- Mil-Handbook-217 FN2 Military Handbook Reliability Prediction Of Electronic Equipment, 28 February 1995

1.3 Method of Analysis

The voltage, current, and power levels, where appropriate for each specific device, were calculated for each of the electrical components in the converter. These levels were then compared to the derated values as per Mil-Hdbk-1547. If derated values were not provided in Mil-Hdbk-1547, Mil-Std-975M or Electronic Derating for Optimum Performance were used.

The stress & derating analysis is performed in order to examine whether all parts used in the system are well suited for their intended use. The analysis is accomplished by comparing the calculated stresses and stress ratios of the device's voltage, current, and power against established derating guidelines. This report calculates the nominal stress values under nominal conditions and the worst case stress under the worst operating (input/output) and environmental conditions.

The setup and function for the stress excel file is described in the following:

The excel file for the stress analysis consists of one main stress sheet, one "Application Data" sheet, and one "Deratings" sheet. On the stress sheet, every component has its own internal part number and reference designator as shown below. The key nominal, worst case and rated/derated quantities for each unique part number are linked to the Deratings sheet. If any changes are made in the Deratings sheet, the rated/derated ratio numbers are automatically updated. The Application Data sheet contains results for other part characteristics not listed on the main stress sheet such as capacitor ripple current or FET gate voltage.

Ref Des	Part Type	Description	Value	Nominal Voltage	Worst Case Voltage	Rated Voltage	Nominal Derated Voltage	Worst Case Derated Voltage	(Rated) Nominal Voltage Stress Ratio	(Rated) Worst Case Stress Ratio	Nominal Derated Voltage Stress Ratio	Worst Case Derated Stress Ratio
C10	GRM155F50J105ZE01D	CAP CER 1U-6.3V-Z-0402-TR-Y5V		5.00	5.20	6.30	3.15	4.41	0.794	0.825	1.587	1.179
C11	0402ZD104KAT2A	CAP CER 0.10U 10V 10% 0402 X5R		5.00	5.20	10.00	5.00	7.00	0.500	0.520	1.000	0.743
C12	0402ZD104KAT2A	CAP CER 0.10U 10V 10% 0402 X5R		5.00	5.20	10.00	5.00	7.00	0.500	0.520	1.000	0.743
C13	0402ZD104KAT2A	CAP CER 0.10U 10V 10% 0402 X5R		5.00	5.20	10.00	5.00	7.00	0.500	0.520	1.000	0.743
R1	ERJ1TRQJ2R2U_R1	RES-TF- 1W- 2.2 -J-2512N	2.2	1.10	1.10	200.00	160.00	160.00	0.006	0.006	0.007	0.007
R10	RK73H1ETTP4751F	RES 4K75 1% 50V 0.063W 0402 mf	4750	5.00	5.20	50.00	40.00	40.00	0.100	0.104	0.125	0.130
R100	RK73H1ETTP6982F	RES 69K8 1% 50V 0.063W 0402 mf	69800	24.49	25.49	50.00	40.00	40.00	0.490	0.510	0.612	0.637
R101	NRC04F1002TRF	RES MF 10.0K 1% .063W 0402	10000	0.00	5.20	50.00	40.00	40.00	0.000	0.104	0.000	0.130
R104	RK73B2BTTD121J	RES 120R 5% 200V 0.250W 1206 mf	120	1.11	1.23	200.00	160.00	160.00	0.006	0.006	0.007	0.008

Note: V-voltage, I-current, P-power.

In order to determine the stress ratio, the nominal (Nom) and worst case (WC) voltage/current/power for each component in the circuit are computed based on the operating conditions. Nom/WC stress ratio is equal to Nom/WC derated V/I/P divided by Nom/WC V/I/P. If stress ratio is larger than 1, then the part is considered to be overstressed and flagged in the left most columns. The stress number will be highlighted in purple if the ratio is between 0.85 - 1 which may be of concern. The stress number will be highlighted in RED if the ratio is larger than 1 (i.e. an overstressed part based on the DERATED quantity versus what the part actually sees in operation.

Ref Des	Part Type	Description	Nominal Tboard		WC Tboard	WC Temperature
D31	MBRS360T3G	DIO-MBRS360-SCHTTY-3A-SM	25.00	81.20	67.00	105.20
K1	EC2-5NJ	RELAY-DPDT-5V 1780HM-2C	25.00	42.50	67.00	76.90
K2	EC2-5NJ	RELAY-DPDT-5V 1780HM-2C	25.00	41.50	67.00	76.90
K3	EC2-5NJ	RELAY-DPDT-5V 1780HM-2C	25.00	41.40	67.00	76.90

Date: 6/16/2011

The Nom/WC temperatures are also included on the stress sheet since temperature can affect the stress results. The nominal temperature for each part is assumed to be the board temperature. The WC temperature is based on the board temperature. The

temperature values are used in deratings sheet to determine the derating percentage for either cliff or linear deratings. The case and junction temperatures are also compared with the rated/derated temperature values for the part.

Capacitor Part Numbers	Rated Voltage	Nominal Voltage Derating	Worst Case Voltage Derating	Nominal Derated Voltage	Worst Case Derated Voltage	Rated Current	Nominal Current Derating	Worst Case Current Derating	Nominal Derated Current	Worst Case Derated Current	Rated Power	Nominal power Derating	Worst Case power Derating	Nominal Derated power	Worst Case Derated power	Resistance	WC Temperature	Nominal Temperature	Mil-spec	Max Nom Junction Temp	Max WC Junction Temp	Note
EMV-160ADA100MD55G	16	80%	0%	12.8	0												67	25	EDOP			Aluminum
GRM155F50J105ZE01D	6.3	50%	70%	3.15	4.41												67	25	1547			Chip, Ceramic
04025A6R8CAT2A	50	50%	70%	25	35												67	25	1547			Temp Compensat, Ceramic (CC,
Diode Part Numbers																						
LL4148	100	70%	70%	70	70	2	50%	50%	1	1	0.5	100%	100%	0.5	0.5		67	25	1547	105	105	Small Signal Fast Switching Diode,
BZD27C36P											0.8	50%	50%	0.4	0.4		67	25	1547	105		Zener, Ta = 25C
SM6T36A						100	75%	75%	75	75	600	75%	75%	450	450		67	25	1547	105	105	Clamping diode,
Transistor Part Numbers																						
BCP56T1G	80	70%	70%	56	56	1	75%	75%	0.75	0.75	1.5	50%	50%	0.75	0.75		90.6	55.3	1547	105		NPN Bipolar
DDTC114YCA-7-F	50	70%	70%	35	35	0.07	75%	75%	0.0525	0.0525	0.2	50%	50%	0.1	0.1		67	25	1547	105		Prebiased NPN Bipolar Transistor,
MOSFET Part Numbers																						
IRFR9024NCTRPBF	55	75%	75%	41.25		8	75%	75%	6	6	38	50%	50%	19	19		67	25	1547	105		P-channel FET
2N7002LT1G	60	75%	75%	45	45	0.8	75%	75%	0.6	0.6	0.225	50%	50%	0.1125	0.1125		67	25	1547	105	125	N-channel FET
Inductor Part Numbers																						
B82462G4472M						2	100%	100%	2	2							67	25				SMT Inductor
CDR74NP-101MC						0.52	100%	100%	0.52	0.52							67	25				SMD Inductor
B82464G4223M000						2.25	100%	100%	2.25	2.25							67	25				SMT Inductor

On the Deratings sheet, part numbers are listed. The rated voltage/current/power, found usually on the datasheet, are entered in the corresponding columns. If two parts that use the same part number have different temperatures that would affect the deratings, two separate deratings rows are used with an added suffix (the reference designator) to distinguish between the two parts.

The derated voltage/current/power is then computed based on the rated number and deratings percentage, i.e. Derated number = Derating % * Rated number. The nominal and WC temperatures are extracted from the stress sheet.

1.4 Nominal and Worst Case Stress Analysis Results

12V Converter Worst Case Stress.xls

C1	06035C104KAT2A	5 8 8 9 9 9 9 9 9 9 9 9 9 9 9 9 9 9 9 9	Value	Nominal Voltage	Worst Case Voltage	S Rated S Voltage	Nominal S Derated S Voltage	Worst Case 55 Derated 00 Voltage	(Rated) Nominal Notrage Stress Ratio	(Rated) Worst Case Stress Ratio	Nominal Derated Voltage Stress Ratio	Stress Ratio	Nominal	Current Worst Case	Current Rated Current	Nominal Case Derated Current	Worst Case Derated Current	(Rated) Nominal Current Stress Ratio	(Rated) Worst Case Stress Ratio Nominal Derated Current	Worst Case Derated Stress Ratio	Current Notes Nominal	Power Worst Case	Power Dated Dougs	Nominal Case Derated Power	Worst Case Derated Power	(Rated) Nominal Power Stress Ratio (Rated) Worst Case	Nominal Derated Power Stress Ratio Worst Case Derated	Stress Ratio
C10	04025C221KAT2A 04025A470JAT2A	CAP CER 220P 50V 10% 0402 X7R CAP CER 47P 50V 5% 0402 C0G		40		50.00		35.00 35.00	0.800	0.864	1.600 1	031	56 48															#
C12	06035C104KAT2A 06035C104KAT2A	CAP CER .1uF 50V 10% X7R 0603		3.712		50.00	25.00	35.00	0.074	0.079	0.148		43															
C13	06035C104KAT2A 06035C104KAT2A	CAP CER .1uF 50V 10% X7R 0603 CAP CER .1uF 50V 10% X7R 0603	+	0.005	2.00E-02 11.55	50.00 50.00		35.00 35.00	0.000	0.000		.330	35									_						+
C15	GRM21BR71H474KA88L	CAP-CC47M- 50V-K-0805-X7R		11.3	12.5	50.00	25.00	35.00	0.226	0.250	0.452 0	40, From	1															
	06035C104KAT2A	CAP CER .1uF 50V 10% X7R 0603		27.1809	29.1809	50.00		35.00	0.544	0.584	1.087	.834	15															\pm
	06035C103JAT2A 06035C103JAT2A	CAP CER 10N 50V 5% 0603 X7R CAP CER 10N 50V 5% 0603 X7R		11.293	12.478	50.00		35.00 35.00	0.226	0.250			23									-	-					+-
C19	06035C104KAT2A GRM32ER71H475KA88L	CAP CER .1uF 50V 10% X7R 0603 CAP CER 4.7uF 50V 10% 1210 X7R		2.495 27.1809	2.525 29.1809	50.00		35.00 35.00	0.050 0.544	0.051	0.100 0	.072	30															
	C0402C103K5RAC	CAP CER 10000P 50V 10% 0402 X7R		2.5	29.1609	50.00	25.00	35.00	0.050	0.051	0.100 0	.072	25															\pm
C3 C4	GRM32ER71H475KA88L GRM31CR61E106KA12L	CAP CER 4.7uF 50V 10% 1210 X7R CAP CER 10U 25V 10% 1206 X5R		12.065	13,356	50.00 25.00	25.00 12.50	35.00 17.50	0.560 0.483	0.600	1.120 0 0.965 0	.763	6									-	-					_
C5 C6 C7	GRM31CR61E106KA12L 06035C104KAT2A	CAP CER 10U 25V 10% 1206 X5R CAP CER 1UF 50V 10% X7R 0603		12	13.2	25.00		17.50 35.00	0.480	0.528	0.960	754	8 47															
C7	04025C102KAT2A	CAP CER 1000P 50V 10% 0402 X7R		2.8	2.8	50.00	25.00	35.00	0.056	0.056	0.112 0		44															
C8 C9	UVR1J100MDD1TD C0402C103K5RAC	CAP-AL 10U-20-63V CAP CER 10000P 50V 10% 0402 X7R		27.2 3.712		63.00 50.00		0.00 35.00	0.432	0.463		<mark>//0!</mark> .113	43		-					+		-	-				_	+
D1	SM4007 (ROHS COMP)	DIO-SM4007 -SI 1A 1KVSM		28	30	1000.00		700.00	0.028	0.030			2 1.19E	-01 3.30E-	01 1.00E+00	5.00E-01	0.500	0.119	0.330 0.2	38 0.660 55, avera	2							=
																				current in	ī							
D2	BYM13-60-E3/25	DIODE SCHOTTKEY BYM13-60		40	43.2	60.00	42.00	42.00	0.667	0.720	0.952	.029 Not use		-01 1.50E+	00 3.00E+01	1.50E+01	15.000	0.008	0.050 0.0	17 0.100 nominal,	peak		-	1	1			+
D3	BAV70 SMBJ28CA-13-F	DIODE UNI BAV70 SOT23				70.00	49.00	49.00	0.000	0.000	0.000	.000 reverse	1.20E	-02 1.70E-		1.00E-01	0.100	0.060	0.085 0.1		38 1 1 40F	04 4 505	04 000 00	0 450 000	450.000	0.000	0.000	200
D5	SMBJ28CA-13-F	PROTECT SMBJ28CA TVS 45.4V Bi PROTECT SMBJ28CA TVS 45.4V Bi												+00 0.00E+		9.90E+00 9.90E+00	9.900	0.000	0.000 0.0 0.000 0.0		10 0.00E	+00 0.00E		0 450.000	450.000 450.000	0.000 0.00 0.000 0.00	0.000 0.0	000 10
D6	MMSZ4698T1G DO1608C-103MLC	DIODE ZEN MMSZ4698 SOD123 11V 5% 0.5W COIL-10UH-M-1.1A -SMT											2.50E	-01 6.00E-	01 1.20E+00	1.20E+00	1,200	0.208	0.500 0.2	08 0.500	1.78E	-02 2.17E	-02 0.50	0.250	0.250	0.036 0.04	0.071 0.0	.87 36
L4		COIL-10UH-M-1.1A -SMT												-01 3.30E-		1.20E+00	1.200	0.099	0.275 0.0		4							
																												28, Current
LED	1 APHK1608SYC	LED-1608-ST-YL-CL-CL-SMT		0.995	1.095	5.00	5.00	5.00	0 199	0.219	0.199	26, Stea 219 state		+00 6.00E-	04 1.50E-01	1.13E-01	0.113	0.000	0.004 0.0	28, Curre 00 0.005 Limit in V		-00 1 06F	-03 0.12	5 0.063	0.063	0.000 0.00	0.000 0.0	Limit in
Q1	NTD3055L104G	FET N-CAN POWER NTD3055L104 369C-01		28	30	60.00		45.00	0.467	0.500			1.19E	-01 1.70E-	01 1.20E+01	9.00E+00	9.000	0.010	0.014 0.0	13 0.019	53 2.70E	-02 3.80E	-02 1.75	0 0.875	0.875	0.015 0.02	0.031 0.0	
R1	BCX19LT1G 2322 734 61009	TRA-BCX19 -NPN-SI SM RES 10E 1% 150V 0,125W 0805 MF	10 3	3.97E-02	0.11	45.00 150.00	31.50 120.00	31.50 120.00	0.622	0.667	0.000	.001	1.20E	-02 1.70E-	02 5.00E-01	3.75E-01	0.375	0.024	0.034 0.0	32 0.045	37 0.00E- 1.58E		-01 0.22 -03 0.12	5 0.113 5 0.063	0.113	0.000 1.53 0.001 0.01	0.000 3.0 0.003 0.0	
	NRC04F1002TRF NRC04F1002TRF	RES MF 10.0K 1% .063W .0405 1000 RES MF 10.0K 1% .063W .0407 1000		17 20661157		50.00		40.00	0.340	0.391			34								2.89E					0.462 0.61	0.925 0.8	
R12	2322 734 61009	RES 10E 1% 150V 0,125W 0805 MF	10	20001107	0.040000177	150.00	120.00	120.00	0.000	0.000	0.000	.000	57								9.30E	-02 1.09E	0.12	5 0.063	0.094	0.744 0.87	1.488 1.1	163 57
R13	RK73H2BTTD1001F RK73H1ETTP3922F	RES 1K 1% 200V 0.250W 1206 100 RES 39K2 1% 50V 0.063W 0402 mf 3920		2.488	2.737	200.00	40.00	160.00 40.00	0.005	0.006	0.006 0	.068	42								1.00E 1.58E		-03 0.25 -04 0.06			0.004 0.00 0.003 0.00	0.008 0.0 0.005 0.0	
	NRC04F1002TRF NRC04F1002TRF	RES MF 10.0K 1% .063W 0408 1000 RES MF 10.0K 1% .063W 0409 1000		20661157	0.049586777	50.00 50.00		40.00 40.00	0.000	0.001	0.001 C		19								4.27E 5.67E	-08 2.46E	-07 0.06 -05 0.06			0.000 0.00 0.001 0.00	0.000 0.0 0.002 0.0	
KIO	NICONI 1002TKI	NES WII 10.0K 1/8 .003W 0409		0.733	0.032	30.00	40.00	40.00	0.013	0.017	0.015		21								3.072	-03 0.921	0.00	0.001	0.047	0.001	0.002 0.0	27,
												27, Curr Limit in	ent															Current Limit in
R17	NRC04F4321TRF NRC04F1002TRF	RES MF 4.32K 1% .063W 0402 433 RES MF 10.0K 1% .063W 0406 1000		0.672	2.592 0.687	50.00 50.00	40.00	40.00 40.00	0.000	0.052		065 WC	22								0.00E-	-05 4.72F				0.000 0.02 0.001 0.00	0.000 0.00 0.001 0.00	
				0.072	0.007							No Stea	dy								4.321	-03 4.720						
R19 R2	MCR01MZSF2001 RK73B2BTTD100J	RES-CHIP 2K-1-0402-100-0.063 200 RES 10R 5% 200V 0.250W 1206 mf		6.00E-02	6.00E-02	50.00 2 200.00	40.00 160.00	40.00 160.00	0.000	0.000	0.000 0	.000 State	52								3.60E	-04 3.60E	0.06 -04 0.25		0.047	0.000 0.00 0.001 0.00	0.000 0.0	
R20	NRC04F1002TRF NRC04F1002TRF	RES MF 10.0K 1% .063W .0410 1000 RES MF 10.0K 1% .063W .0411 1000		0.0004	0.005	50.00		40.00	0.000	0.000			24									-11 2.50E				0.000 0.00	0.000 0.0	
				2.0	2.023							14, No								1	0.250	, 0.00E						
R22	RK73H1ETTP1001F 2322 734 61009	RES 1K0 1% 50V 0.063W 0402 mf 100 RES 10E 1% 150V 0.125W 0805 MF	10 3	3.97E-02	0.11	50.00 150.00	40.00 120.00	40.00 120.00	0.000	0.000	0.000	.000 Steady .001	49		_						1.58E			5 0.063	0.094	0.000 0.00 0.001 0.01	0.000 0.0	013 49
R24	2322 734 61009 NRC04F1002TRF	RES 10E 1% 150V 0,125W 0805 MF RES MF 10.0K 1% .063W 0412 1000	10 3	3.97E-02 2.5	0.11 2.525	150.00 50.00	120.00	120.00 40.00	0.000	0.001	0.000 0		49									-04 1.21E	-03 0.12	5 0.063	0.094	0.001 0.01 0.010 0.01	0.003 0.0 0.020 0.0	013 49
R26	RK73H1ETTP1503F	RES 150K 1% 50V 0.063W 0402 mf 15000	00	11.293	12.478	50.00	40.00	40.00	0.226	0.250	0.282 0	.312	20								8.50E	-04 1.04E	-03 0.06	3 0.031	0.047	0.014 0.01	0.027 0.03	022 20
R27	RK73H1ETTP1503F	RES 150K 1% 50V 0.063W 0402 mf 15000	00	10.09	10.298	50.00	40.00	40.00	0.202	0.206	0.252 0		23		+					+ + -	6.79E	-04 7.07E	-04 0.06	3 0.031	0.047	0.011 0.01	0.022 0.0	15 23
R20	RK73H1ETTP1001F	RES 1K0 1% 50V 0.063W 0402 mf 100	00			50.00	40.00	40.00	0.000	0.000	0.000	29, Curr	ent		1								0.06	3 0.024	0.047	0.000 0.00	0.000 0.0	200
R29	MCR01MZSF1742	RES 17K4-1-0402-100-0.063 1740			24.03314917	50.00		40.00	0.449	0.481	0.561 0	.601	11								2.89E		-02 0.06		0.047	0.459 0.52	0.918 0.7	703 11
R30	NRC04F1003TRF NRC04F4321TRF	RES MF 100K 1% .063W 0402 10000 RES MF 4.32K 1% .063W 0402 433		4.05 69060773	5.712	50.00 50.00	40.00	40.00 40.00	0.081	0.114	0.139 0		12	_	+					+ + -	7.18E	-04 3.26E -03 8.24E		3 0.031	0.047	0.003 0.00 0.115 0.13	0.005 0.0 0.230 0.1	
R31	CR10-1212-FT 2350 510 12107L	RES 12K1 1% 50V 0.063W 0402 mf 1210 RES 0R1 1% 200V 250mW 1206 0	00	0.025	0.06	50.00	40.00	40.00	0.001	0.001	0.001 0	.002	18								5.17E		- 07 0.06	3 0.031	0.047	0.000 0.00 0.025 0.14	0.000 0.0	000 18
R33	RK73H1ETTP1R82F	RES 1R82 1% 50V 0.063W 0402 tf 1.8	82	0.020	0.00	50.00	40.00	40.00	0.000	0.000	0.000	.000	9								0.00E	0.00E	0.06	3 0.031	0.047	0.000 0.00	0.000 0.0	000 9
R5	ERJ2RKF6651X NRC04F1821TRF	RES 6.65K 1% 50V 63mW 0402 668 RES MF 1.82K 1% .063W 0402 183		9.512 2.488	10.463 2.737	50.00		40.00	0.190	0.209	0.238 0 0.062 0	.068	42	+	+					+ + -	1.36E 3.40E					0.136 0.16 0.054 0.06		19 41 J88 42
R6	NRC04F1002TRF NRC04F1002TRF	RES MF 10.0K 1% .063W 0402 1000 RES MF 10.0K 1% .063W 0403 1000	00	0.0004	0.005	50.00	40.00	40.00	0.000	0.000	0.000 0	.000	17								1.60E	-11 2.50E	-09 0.06	3 0.031	0.047	0.000 0.00 0.000 0.00		000 17
R8	RK73H1ETTP6811F	RES 6K81 1% 50V 0.063W 0402 mf 68	10	3.8	3.85	50.00	40.00	40.00	0.076	0.077	0.095	.096	45								2.12E	-03 2.18E	-03 0.06	3 0.031	0.047	0.034 0.03	0.068 0.0	046 45
R9 T1	NRC04F1002TRF MSD1260-104MLD	RES MF 10.0K 1% .063W 0404 1000 IND FIX 100uH 20% 1,9A 0,161 Ohm SMT	00	5	5.05	50.00	40.00	40.00	0.100	0.101	0.125 0	.126	46 1.19E	-01 3.30E-	01 2.20E+00	2.20E+00	2.200	0.054	0.150 0.0	54 0.150	2.50E	-03 2.55E	-03 0.06	3 0.031	0.047	0.040 0.04	0.080 0.0	54 46
114	UC3843BD1R2G	IC(CURRMODEPWMCTRL) SM08		11.3	40.0	30.00	24.00	24.00	0.377	0.417	0.538 0	39, From	1															
01	LM324MTX/NOPB	IC(LM324)QUAD OPAMP-SM		27 1809	12.5	32.00	21.00	24.00	0.377	0.417	0.530	oz i suipul									1.63E	-01 3 50E		0 0.600		0.204 0.43	0.070	33, Total
U3	NCP301LSN30T1G	IC(33464N-30)3V RST CRCT			5.966850829	12.00	8.40	9.60	0.464	0.497	0.663	622	13								1.63E	-01 3.50E	0.80	U.60L	0.080	0.204 0.43	0.272 0.5	13 70

1.5 Summary List of Stress Failures

The following stress failures were found:

Des	t Type	cription	minal	rst Case tage	pe peq	ninal ated tage	rst Case ated tage	ned) ninal tage sss Ratio	rst Case	ninal ated tage sss Ratio	rst Case ated ass Ratio	aget ses	minal	rst Case	ed	ninal se ated rent	rst Case ated rent	nted) minal rent ess Ratio	red) rst Case	ninal ated rent sss Ratio	rst Case ated ass Ratio	rent es minal	wer rst Case	wer	ed Power ninal se ated	ver rst Case ated	ninal ver Stress	rst Case	ninal ated ver Stress io	rst Case ated ass Ratio	ver Notes
20	Par	∑e N	2 2	% ≥	Vol Ra	No	Vol	St o S	Wo Stre	Str. Vol. No.	Str	≥ ≥	S D	دَ ≨	C Rat	COSS	o E N	Stre Stre	Sk (Ra	Non	Str.	5 N S	§ §	ē.	D C S S	8 8 8	R P S R	St. Vo	R P P S	Str	δ
C1	06035C104KAT2A	CAP CER .1uF 50V 10% X7R 0603	27.2	29.2	50.00	25.00	35.00	0.544	0.584	1.088	0.834	3																			
C10	04025C221KAT2A	CAP CER 220P 50V 10% 0402 X7R	40	43.2	50.00	25.00	35.00	0.800	0.864	1.600	1.234	56																			\neg
C16	06035C104KAT2A	CAP CER .1uF 50V 10% X7R 0603	27.1809	29.1809	50.00	25.00	35.00	0.544	0.584	1.087	0.834	15																			\neg
C2	GRM32ER71H475KA88L	CAP CER 4.7uF 50V 10% 1210 X7R	27.1809	29.1809	50.00	25.00	35.00	0.544	0.584	1.087	0.834	5																			\neg
C3	GRM32ER71H475KA88L	CAP CER 4.7uF 50V 10% 1210 X7R	28	30	50.00	25.00	35.00	0.560	0.600	1.120	0.857	54																			\neg
C8	UVR1J100MDD1TD	CAP-AL 10U-20-63V	27.2	29.2	63.00	50.40	0.00	0.432	0.463	0.540	#DIV/0!	3																			\neg
																						55, average current in									
	BYM13-60-E3/25	DIODE SCHOTTKEY BYM13-60	40	43.2	60.00	42.00	42.00	0.667	0.720	0.952	1.029	55		1.50E+00		1.50E+01	15.000	0.008	0.050	0.017	0.100	nominal, peak									
Q2	BCX19LT1G	TRA-BCX19 -NPN-SI SM	28	30	45.00	31.50	31.50	0.622	0.667	0.889	0.952	nput	1.20E-02	1.70E-02	5.00E-01	3.75E-01	0.375	0.024	0.034	0.032	0.045	37 0.00E+	00 3.44E	-01 0.	.225 0.1	13 0.113	0.000	1.530	0.000	3.060 37,	
R12	2322 734 61009	RES 10E 1% 150V 0,125W 0805 MF 10			150.00	120.00	120.00	0.000	0.000	0.000	0.000	57										9.30E-	02 1.09E	- 01 0.	.125 0.0	63 0.094	0.744	0.872		1.163	57
U2	LM324MTX/NOPB	IC(LM324)QUAD_OPAMP-SM	27.1809	29.1809	32.00	22.40	25.60	0.849	0.912	1.213	1.140	32										1.63E-	01 3.50E	-01 0.	.800 0.6	00 0.680	0.204	0.438	0.272	33, To 0.515 Pd	otal

C1: Fail the nominal derated voltage stress.

C10: Fail both the derated voltage stresses.

C16: Fail the nominal derated voltage stress.

C2: Fail the nominal derated voltage stress.

C3: Fail the nominal derated voltage stress.

C8: Fail the worst case derated voltage stress.

D2: Fail the worst case derated voltage stress.

Q2: Fail the RATED power stress.

R12: Fail both the derated power stresses.

U2: Fail both the derated voltage stresses.

1.6 Assumptions

The following assumptions were made in order to complete this analysis.

- The BOM provided multiple manufacturers and part numbers for some of the parts. The
 first manufacturer and part number were used to obtain the electrical ratings. It is
 extremely important that other potential manufacturer's data be reviewed to see if their
 ratings are different.
- Mil-Hdbk-1547 does not include derating guidelines for aluminum electrolytic capacitors.
 Derating guidelines from "Electronic Derating for Optimum Performance" published by the Reliability Information Analysis Center have been used for these capacitors.
- Mil-Hdbk-1547 does not include derating guidelines for LEDs. Derating guidelines from
 "Technical Requirements for Electronic Parts, Materials, and Processes Used in Space
 and Launch Vehicles" (TOR) published by The Aerospace Corporation have been used
 for LEDs. The document does not include derating guidelines for reverse voltage; a
 derating of 100% has been used.
- No current derating guidelines exist for inductors and transformers, 100% current deratings have been used.
- The power rating for the MOSFET Q1 is the worst case power rating when the MOSFET is mounted on the minimum pad size recommended.
- Thermal impedances have not been included. Therefore, junction temperature calculations have not been included.
- The temperatures of the components are assumed to be the board temperature; 25C nominal and 67C in the worst case.

The following assumptions are for the stress calculations which can also be found in the MathCAD sheet:

- Nominal input voltage 28V, maximum input voltage 30V, and minimum input voltage 18V from specifications.
- Nominal output voltage 12V, maximum output voltage 13.2V, and minimum output voltage 10.8V from specifications (+/-10%).

- Nominal output current 250mA from 0-500mA range given, maximum output current 600mA from circuit description: "600mA through R32 will trip current limit."
- Nominal efficiency 90%, minimum efficiency 80% from "The module shall be greater than 80% efficient at full load. At light load the efficiency may be less but the module shall generate less than 2.0W waste heat."
- Nominal duty cycle 30%, minimum duty cycle 26.5%, maximum duty cycle 42.3%.
- The rise and fall time of the drive signal from U1 is zero when calculating the losses of the MOSFET Q1.
- Turn off time for the MOSFET is an assumption based on data provided on the datasheet.
 The actual turn off time will be lower because of higher driver voltage and no external gate resistance on the application circuit.
- The input bias current to the opamps was neglected for most calculations in the current limit circuitry.

File: Sample Stress and Derating Report.doc

1.7 Deratings

Table 1.7-1: Component voltage, current, and power deratings used in the nominal and worst case stress & derating analysis. Data can be found in the derating sheet of the Worst Case Stress.xls file.

Capacition Part Numbers Capacition Part		Rated Voltage	ominal Voltage erating	Worst Case Voltage Derating	dominal Derated Voltage	st Case Derated	ed Current	ninal Current ating	Vorst Case Current Perating	vorninal Derated Current	Norst Case Derated Current	ed Power	ominal power Derating	st Case power ating	rinal Derated power	st Case Derated	sistance	/C Temperature	ominal Temperature	sbec	ax Nom Junction Temp	WC Junction Temp	9
	Canacitor Part Numbers	Sat	No.	Noi	ō	\$ ₹	Sat	P Se	No.	٥	اج ک	Şat	호	o No	è	§ §	Şe	ဍ	Š	╘	laĝ	Маў	Ž
MOREGISCHANTAIN 0 0 0 770 2 3 0 0 770 2 3 0 0 0 770 2 3 0 0 0 0 0 0 0 0 0		50	50%		25													67	25	1547	_	_	Chip, Ceramic (CDR)
COMPANDED 1000 70										1													
GRADISPRIANCE SECTION 12 17 17						35																	
GRAZIERTHAYARASASS 0 50°S, 77°S, 25°S 35°S																							
CRASSERTINFFSKASSE																							
Deposit Color No. Property Color P																							
Degrate Application 1000 70% 70% 28 35 90% 70% 50 4 9 9 9 9 9 9 9 9 9																					-		
Diole Part Numbers Sept. Color Sept. Color Sept.																							
Dicide Part Numbers 1900 77% 70%						35															-		
SMADP 1000 70% 70% 700 700 1 50% 50% 50% 0.5	O VICTO TOOMIDD TTD	03	0076	0 /6	30.4	- 0				-						-	 	01	-23	1041			2000 mount, 2100, Alum (OL), rated 600
SMADP 1000 70% 70% 700 700 1 50% 50% 50% 0.5										-						1							
SMADP 1000 70% 70% 700 700 1 50% 50% 50% 0.5	Diode Part Numbers																						
BYM13-06-13:F	SM4007 (ROHS COMP)						1																
SMBJ28CA-13-F							0.2																
MMSZ4698T1G 5 100% 100% 5 5 5 018 75% 75% 0.1125 0.1125 1.25E-011 50% 50% 50% 0.225 0.025		60	70%	70%	42	42	1																
APHRO68SYC S 100% 100% 5 5 0.18 75% 75% 0.1125 0.1125 1.585-01 50% 50% 0.0625 0.6225 67 25 TOR 105 105 LED Ta = 25C							13.2	75%	75%	9.9	9.9												
Translator Part Numbers		-	4000/	4000/	-		0.45	750/	750/	0.4405	0.4405												
BCX19LTIG	APHK1608STC	5	100%	100%	5	5	0.15	75%	75%	0.1125	0.1125	1.25E-01	50%	50%	0.0625	0.0625		67	25	TOR	105	105	LED, 1a = 25C
BCX191TIG	Transistor Part Numbers																						
MOSFET Part Numbers		45	70%	70%	31.5	31.5	0.5	75%	75%	0.3750	0.375	0.225	50%	50%	0.1125	0.1125		67	25	1547	105	125	NPN BJT Transistor
NT03055104G																							
Inductor Part Numbers																							
Dot888C-103MLC	NTD3055L104G	60	75%	75%	45	45	12	75%	75%	9.0000	9	48	50%	50%	24	24		67	25	1547	105	125	N-channel FET
Dot888C-103MLC	Industry Best Newsberg																						
D1698C-103MLD																							
Transformer Part Numbers 22 100% 100% 2.2 2.2 2.2																		_	_				
MSD1260-104MLD	DO1608C-103MLD						1.2	100%	100%	1.2	1.2							67	25				Inductor
MSD1260-104MLD																							
Resistor Part Numbers							0.0	4000/	4.000/	0.0	0.0							07	05				T
150 80% 80% 120	MSD1260-104MLD						2.2	100%	100%	2.2	2.2							67	25				Transformer
150 80% 80% 120	Resistor Part Numbers																						
NRCOGF1002TEF 50 80% 80% 40 40 40 40 40 40 40		150	80%	80%	120	120						0.125	50%	75%	0.0625	0.0938	10	67	25	1547			Film (RL, RLR, RN, RNR, RM)
RK73H2BTT01001F 200 80% 80% 160 160 160 0 0.0625 50% 75% 0.1250 0.1875 1000 67 25 1547 Film (RL, RLR, RN, RNR, RM) CR10-1212-FT 50 80% 80% 40 40 40 0 0.0625 50% 75% 0.0313 0.0469 12100 67 25 1547 Film (RL, RLR, RN, RNR, RM) CR10-1212-FT 50 80% 80% 40 40 40 0 0.0625 50% 75% 0.0313 0.0469 12100 67 25 1547 Film (RL, RLR, RN, RNR, RM) MCR01M2SF2001 50 80% 80% 40 40 40 0 0.0625 50% 75% 0.0313 0.0469 12100 67 25 1547 Film (RL, RLR, RN, RNR, RM) RK73HETTP1001F 50 80% 80% 40 40 40 0 0.0625 50% 75% 0.0313 0.0469 1200 67 25 1547 Film (RL, RLR, RN, RNR, RM) RK73HEITP1001F 50 80% 80% 40 40 40 0 0.0625 50% 75% 0.0313 0.0469 1.000 67 25 1547 Film (RL, RLR, RN, RNR, RM) RK024F1821TRF 50 80% 80% 40 40 40 0 0.0625 50% 75% 0.0313 0.0469 1.000 67 25 1547 Film (RL, RLR, RN, RNR, RM) NRC04F103TRF 50 80% 80% 40 40 40 0 0.0625 50% 75% 0.0313 0.0469 1.000 67 25 1547 Film (RL, RLR, RN, RNR, RM) NRC04F103TRF 50 80% 80% 40 40 40 0 0.0625 50% 75% 0.0313 0.0469 1.000 67 25 1547 Film (RL, RLR, RN, RNR, RM) NRC04F103TRF 50 80% 80% 40 40 40 0 0.0625 50% 75% 0.0313 0.0469 1.000 67 25 1547 Film (RL, RLR, RN, RNR, RM) NRC04F103TRF 50 80% 80% 40 40 40 0 0.0625 50% 75% 0.0313 0.0469 1.000 67 25 1547 Film (RL, RLR, RN, RNR, RM) NRC04F103TRF 50 80% 80% 40 40 40 0 0.0625 50% 75% 0.0313 0.0469 1.000 67 25 1547 Film (RL, RLR, RN, RNR, RM) NRC04F103TRF 50 80% 80% 40 40 40 0 0.0625 50% 75% 0.0313 0.0469 1.000 67 25 1547 Film (RL, RLR, RN, RNR, RM) NRC04F103TRF 50 80% 80% 40 40 40 0 0.0625 50% 75% 0.0313 0.0469 1.000 67 25 1547 Film (RL, RLR, RN, RNR, RM) NRC04F103TRF 50 80% 80% 40 40 40 0 0.0625 50% 75% 0.0313 0.0469 1.000 67 25 1547 Film (RL, RLR, RN, RNR, RM) NRC04F103TRF 60 80% 80% 40 40 40 60 60 60 60 60 60 60 60 60 60 60 60 60																							
CR10-1212-FT 50	RK73H2BTTD1001F		80%	80%	160	160						0.25	50%	75%	0.1250	0.1875	1000	67	25	1547			Film (RL, RLR, RN, RNR, RM)
MCR01MZSF2001 50 80% 80% 40 40 40 40 40 40 40																							
RK73B2BTTD100J 200 80% 80% 160																							
RX73HETTP1001F 50 80% 80% 40 40 40																							
NRC04F1821TRF 50 80% 80% 40 40 40 40 40 40 40										-											-	-	
NRCO4F1003TRF 50 80% 80% 40 40 40 40 40 40 40							\vdash														-		
ERJ2RKF6651X 50 80% 80% 40 40 0.1 50% 75% 0.0500 0.0750 6650 67 25 1547 Film (RL, RLR, RN, RNR, RM) RK73H1ETTP1503F 50 80% 80% 40 40 0.0625 50% 75% 0.0313 0.0469 1.50±40 67 25 1547 Film (RL, RR, RN, RNR, RM) MCR01MS2F1742 50 80% 80% 40 40 0.063 50% 75% 0.0313 0.0469 1.50±40 67 25 1547 Film (RL, RR, RN, RNR, RM) RK73H1ETTP681F 50 80% 80% 40 40 0.0625 50% 75% 0.0313 0.0469 6.81±40 67 25 1547 Film (RL, RR, RN, RNR, RM) RX73H1ETTP681F 50 80% 40 40 0.0625 50% 75% 0.0313 0.0469 6.81±40 67 25 1547 Film (RL, RR, RN, RNR, RM) 235 50 12120TL 200 80%										-													
RX73H1ETTP1503F 50 80% 80% 40 40 40 40 40 40 40 40 40 40 40 40 40										-													
MCR01M2SF1742 50 80% 80% 40 40 0.063 50% 75% 0.0313 0.0473 174E-04 67 25 1547 Film (RL, RR, RN, RR, RM) RK73H1ETP6811F 50 80% 80% 40 40 0.0625 50% 75% 0.0313 0.043 1.724E-04 67 25 1547 Film (RL, RR, RN, RR, RM) 2350 510 12107L 200 80% 80% 160 160 0.25 50% 75% 0.1250 0.1875 1.00E-01 67 25 1547 Film (RL, RR, RN, RR, RM) NRC04F321TRF 50 80% 40 40 0.0025 50% 75% 0.0313 0.0469 4.52E-403 67 25 1547 Film (RL, RR, RN, RNR, RM) NRC03H2TP1F18R2F 50 80% 40 40 0.0625 50% 75% 0.0313 0.0469 4.52E-403 67 25 1547 Film (RL, RR, RN, RNR, RM) Linear Device 50 80%										1													
2350 510 12107L 200 80% 80% 160 160																							
NRC04F4321TRF 50 80% 80% 40 40 0.0625 50% 75% 0.0313 0.0469 4.32E+03 67 25 1547 Film (RL, RLR, RN, RNR, RM) RK73H1ETTP1R82F 50 80% 80% 40 40 0.0625 50% 75% 0.0313 0.0469 1.82E+00 67 25 1547 Film (RL, RLR, RN, RNR, RM) Linear Device 1												0.0625											
RK73H1ETTP1R82F 50 80% 80% 40 40 40 0.0625 50% 75% 0.0313 0.0469 1.82E+00 67 25 1547 Film (RL, RLR, RN, RNR, RM) Linear Device																							
Linear Device																							
	RK/3H1ETTP1R82F	50	80%	80%	40	40						0.0625	50%	75%	0.0313	0.0469	1.82E+00	67	25	1547	-	_	Film (RL, RLR, RN, RNR, RM)
	Linear Device																						
10000000000000000000000000000000000000		30	70%	80%	21	24	- 1	750/	850/	0.75	0.05	0.702	750/	850/	0.5265	0.5967		67	25	15/17	105	125	Current Mode Controller
LM324MTX/NOPB 32 70% 80% 22.4 25.6 0.8 75% 85% 0.6000 0.6800 67 25 1547 105 125 Op Amp		00						1570	00%	0.75	0.00												
NCP3011SN3071G 12 70% 80% 8.4 9.6 5 5 5 5 5 7 7 7 7 7 7 7 7 7 7 7 7 7 7										- 1		0.0	. 0 /0	3370	0.0000	0.0000							

1.8 Conclusion

Both the nominal and worst case stress analyses were completed for the 12V Converter Module. This report contains the latest nominal stress results along with the worst case stress results.

In the process of the analysis, several stress failures were uncovered. Most of the stress failures are the result of the derating factors, and most are marginally over the derated stress. Q2 fails the power rating but only conducts during startup.

These failures, listed in Section 1.5, "Summary List of Stress Failures" should be examined closely.

The following conclusions have been made for this analysis:

- The manufacturer of aluminum electrolytic capacitor C8 has rated the part's maximum temperature as 85C. The document EDOP has a cliff derating for this part type at 65C. The maximum temperature of the board is 67C. Therefore, at any applied voltage, the part will always fail the derated voltage.
- The worst case power dissipation calculated for Q2 is for startup when the output voltage has not risen to provide power for U1. It fails the rated power; however, the power dissipation is brief because the output voltage rises in a matter of a few milliseconds. When current limit occurs, the output voltage drops and may not turn on its OR diode, causing Q2 and its OR diode to turn on. Current limit should not be sustained for long periods otherwise the transistor may be burned.
- There is no steady state stress on the damping resistor R33. However, AC or dynamic current can overstress the component.
- The BOM provided multiple manufacturers and part numbers for some of the parts. The first manufacturer and part number were used to obtain the electrical ratings. It is extremely important that other potential manufacturer's data be reviewed to see if their ratings are different.

Other Potential Concerns

Both AC and transient domain SPICE models were created for the 12V converter. Several

simulations were performed to analyze potential stress and design issues relating to the circuitry

based on the specification and ratings from the individual parts.

During the initial turn on, the output voltage can overshoot substantially, due to the lack of

damping in the filter. This may be minimized, but the rise time of the input, though the 28V

boost has a diode connected directly from its input to its output.

The output voltage loop does not include soft-start, and more importantly, does not include a

fault-recovery soft-start.

The opamp supply voltage is dangerously close to its maximum Vcc rating in normal operation

and exceeds it as a result of the undamped input filter.

The SEPIC coupling capacitor, C3, is also undamped. This may cause control loop issues, though

it appears that the control loop bandwidth is very low.

R33 is used to damp the ringing from L3, C5, however, the spec allows up to 1000uF of external

capacitance which will not be damped by R33. Additionally, the output capacitors, C4 and C5,

are X5R. These capacitors have very substantial tolerances, as well as, a very significant DC Bias

effect. It will be important to understand the DC Bias effect of the particular capacitors you have

chosen.

The output transient suppressor, D5, is designed to be placed on a 28V bus. The working voltage

and the clamping voltage are well above the rating of the output capacitors and also well above

the rating of the output diode, D2.

1-13

There is insufficient information regarding parasitic elements to determine the ringing on D2. In the absence of ringing, the diode voltage is Vout + Vin which may exceed the rating of the diode. This is especially true in the recovery from an overload condition.

While there is currently no plan to perform WCCA on this module, we did want to point out some of the more obvious concerns. You may wish to do some testing to verify some of these concerns, especially given that many of them can result in catastrophic failures. The stability of this converter is poor even under the best of conditions. The large load current range, load capacitance range and undamped resonances greatly exacerbate the issues.